

Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D $T_A = +25^\circ\text{C}$
-250V	$14\Omega @ V_{GS} = 10V$	-265mA

Description

This new generation trench MOSFET features a unique structure combining the benefits of low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Applications

- Earth Recall and Dialling Switches
- Electronic Hook Switches
- High Voltage Power MOSFET Drivers
- Telecom Call Routers
- Solid State Relays

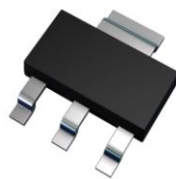
Features and Benefits

- High Voltage
- Low On-resistance
- Fast Switching Speed
- Low Gate Drive
- Low Threshold
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

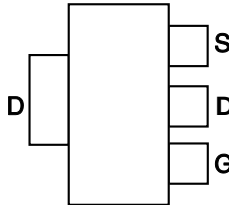
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (e3)
- Weight: 0.112 grams (Approximate)

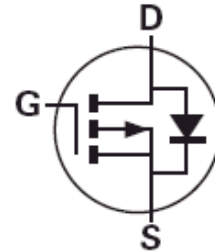
SOT223



Top View



Pin Out - Top



Equivalent Circuit

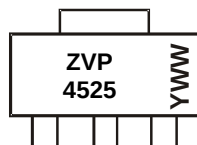
Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZVP4525GTA	ZVP4525	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT223



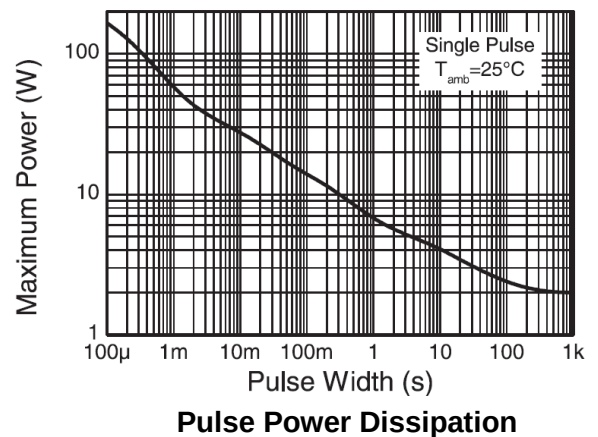
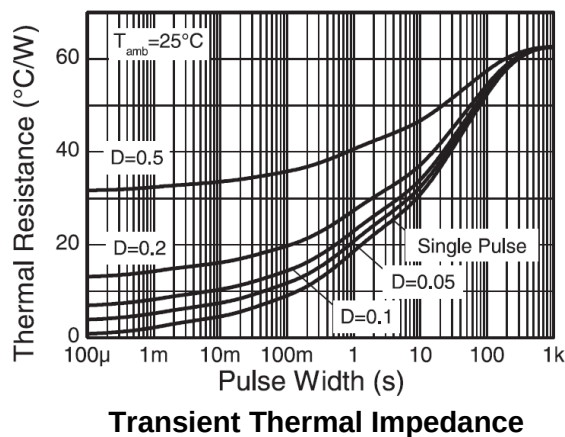
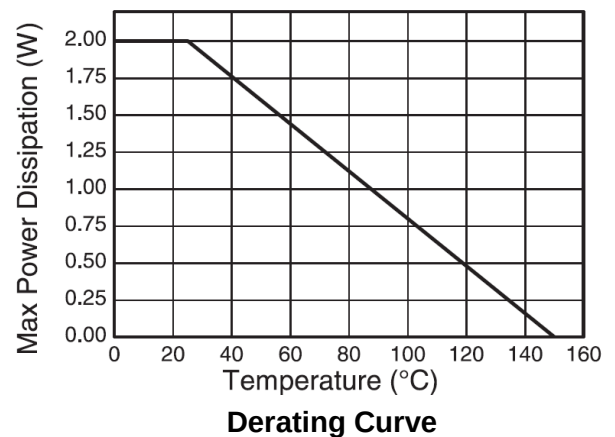
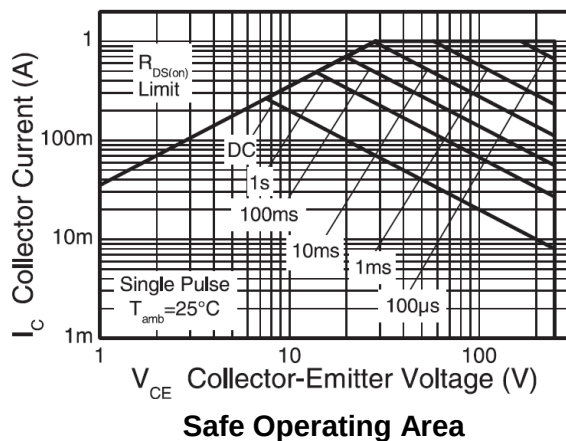
ZVP4525 = Product Type Marking Code
 YWW = Date Code Marking
 Y or Y = Last Digit of Year (ex: 5 = 2015)
 WW or WW = Week Code (01~53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	-250	V
Gate-Source Voltage	V _{GSS}	±40	V
Continuous Drain Current @V _{GS} = 10V; T _A = +25°C (Note 5)	I _D	-265	mA
@V _{GS} = 10V; T _A = +70°C (Note 5)		-212	
Pulsed Drain Current (Note 7)	I _{DM}	-1	A
Continuous Source Current (Body Diode)	I _S	-0.75	A
Pulsed Source Current (Body Diode)	I _{SM}	-1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation at T _A = +25°C (Note 5)	P _D	2.0	W
Linear Derating Factor		16	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	63	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	26	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

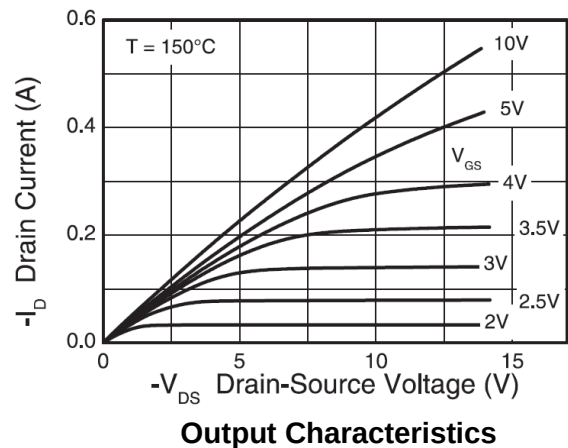
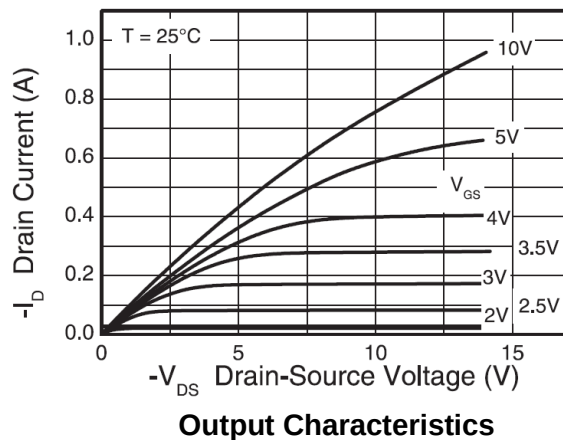


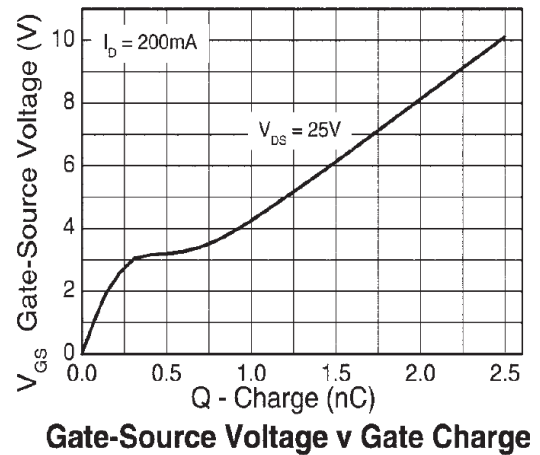
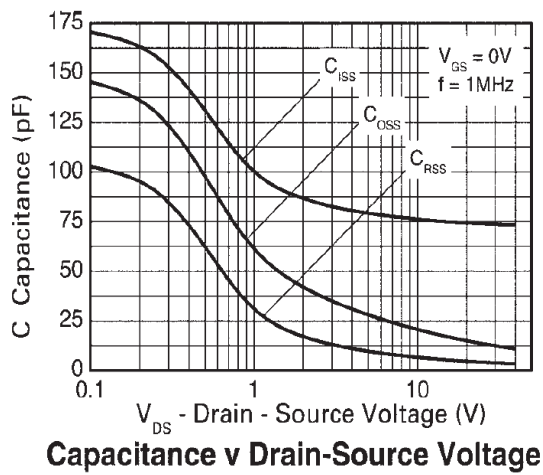
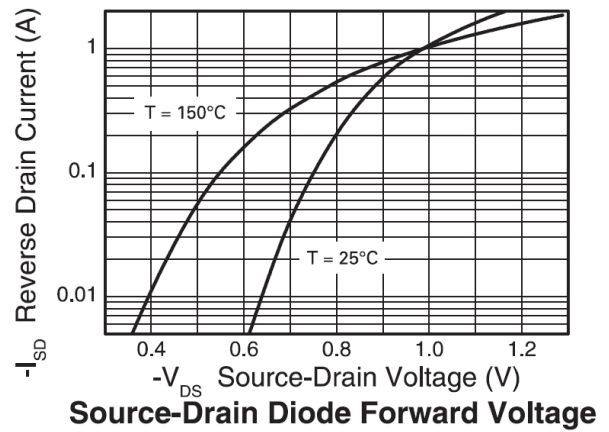
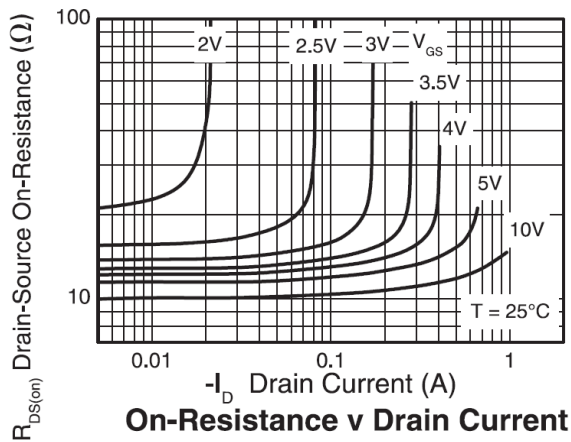
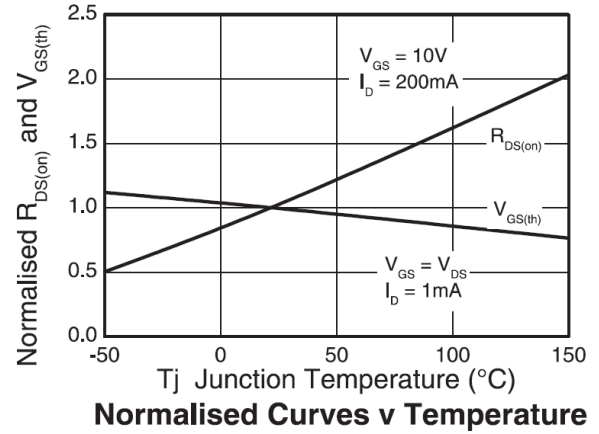
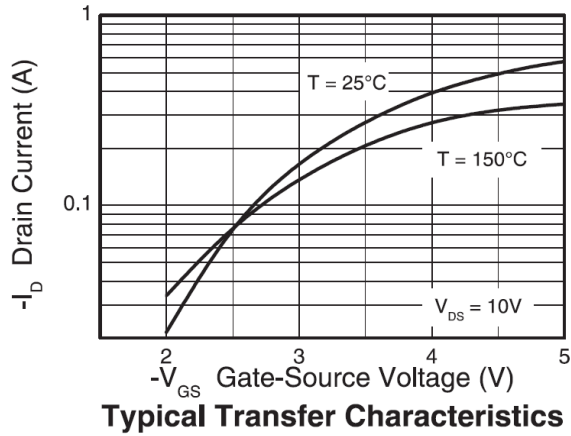
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	-250	-285	-	V	V _{GS} = 0V, I _D = -1mA
Zero Gate Voltage Drain Current	I _{DSS}	-	-30	-500	nA	V _{DS} = -250V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	-	±1	±100	nA	V _{GS} = ±40V, V _{DS} = 0V
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	-0.8	-1.5	-2.0	V	V _{DS} = V _{GS} , I _D = -1mA
Static Drain-Source On-Resistance (Note 8)	R _{DS(ON)}	-	10	14	Ω	V _{GS} = -10V, I _D = -200mA
		-	13	18	Ω	V _{GS} = -3.5V, I _D = -100mA
Forward Transconductance (Note 10)	g _{fs}	80	200	-	mS	V _{DS} = -10V, I _D = -0.15A
Diode Forward Voltage (Note 8)	V _{SD}	-	-	0.97	V	I _S = -200mA, V _{GS} = 0V, T _J = +25°C
DYNAMIC CHARACTERISTICS						
Input Capacitance (Note 10)	C _{iss}	-	73	-	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance (Note 10)	C _{oss}	-	12.8	-	pF	
Reverse Transfer Capacitance (Note 10)	C _{rss}	-	3.91	-	pF	
Total Gate Charge (Notes 9 & 10)	Q _g	-	2.45	3.45	nC	V _{GS} = -10V, V _{DS} = -25V I _D = -200mA
Gate-Source Charge (Notes 9 & 10)	Q _{gs}	-	0.22	0.31	nC	
Gate-Drain Charge (Notes 9 & 10)	Q _{gd}	-	0.45	0.63	nC	
Turn-On Delay Time (Notes 9 & 10)	t _{D(ON)}	-	1.53	-	ns	V _{DD} = -30V, I _D = -200mA, V _{GS} = -10V, R _G = 50Ω
Turn-On Rise Time (Notes 9 & 10)	t _R	-	3.78	-	ns	
Turn-Off Delay Time (Notes 9 & 10)	t _{D(OFF)}	-	17.5	-	ns	
Turn-Off Fall Time (Notes 9 & 10)	t _F	-	7.85	-	ns	I _F = -200mA, di/dt = 100A/μs, T _J = +25°C
Reverse Recovery Time (Note 10)	t _{RR}	-	205	290	ns	
Reverse Recovery Charge (Note 10)	Q _{rr}	-	21	29	nC	

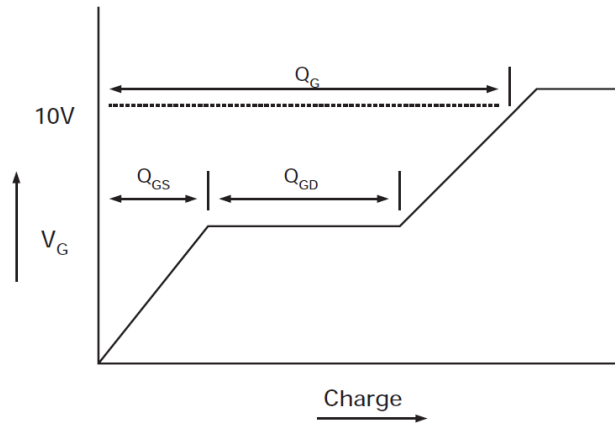
Notes:

- For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- For a device surface mounted on FR4 PCB measured at t ≤ 5 secs.
- Repetitive rating 25mm x 25mm FR4 PCB, D=0.02 pulse width=300μs - pulse width limited by maximum junction temperature.
- Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
- Switching characteristics are independent of operating junction temperature.
- For design aid only, not subject to production testing.

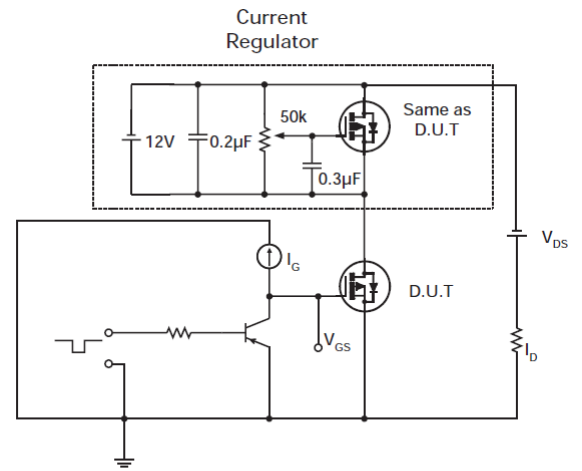




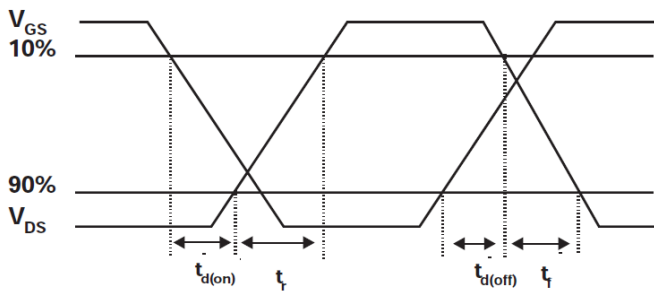
Test Circuits



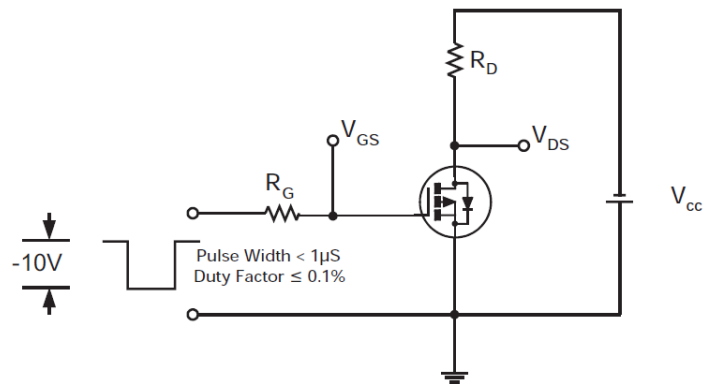
Basic Gate Charge Waveform



Gate Charge Test Circuit



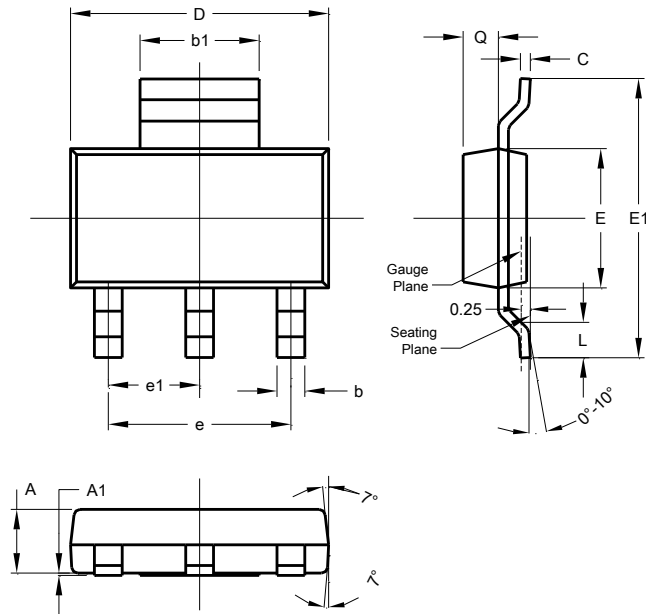
Switching Time Waveforms



Switching Time Test Circuit

Package Outline Dimensions

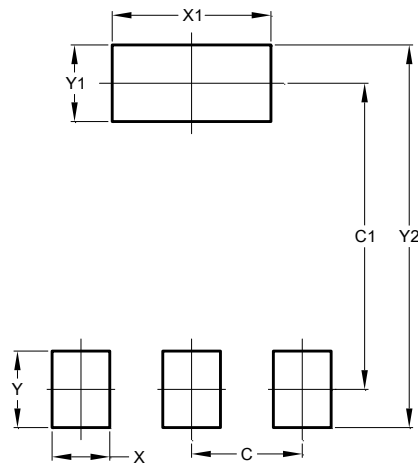
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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